



A Product Line of Diodes Incorporated



**FMMT491** 

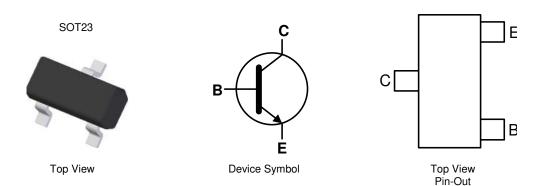
#### **60V NPN MEDIUM POWER TRANSISTOR IN SOT23**

### Feature

- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 1A Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- $R_{CE(sat)} = 195m\Omega$  for a Low Equivalent On-Resistance
- 500mW Power Dissipation
- hFE Characterized up to 2A for High Current Gain Hold up
- Complementary PNP Type: FMMT591
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded plastic, "Green" Molding Compound
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (Approximate)



## Ordering Information (Note 4)

•					
Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT491TA	AEC-Q101	491	7	8	3,000
FMMT491TC	AEC-Q101	491	13	8	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**









## **FMMT491**

#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ι <sub>C</sub>	1	А
Peak Pulse Current	I <sub>CM</sub>	2	А
Base Current	IB	200	mA

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)	R <sub>θJL</sub>	197	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

#### ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

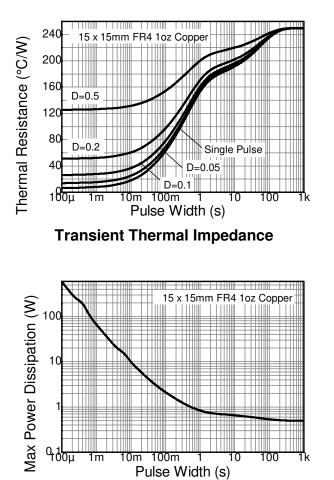
5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state.

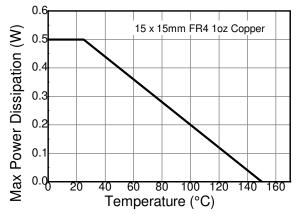
Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.





# **Thermal Characteristics and Derating Information**





**Derating Curve** 







**FMMT491** 

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

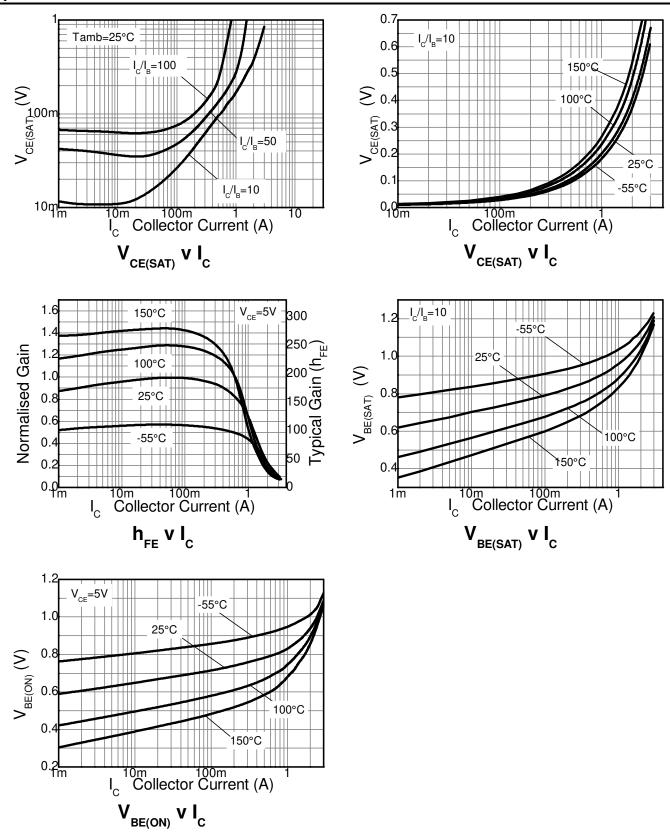
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	80	—	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	60	—	—	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.1	—	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	—	<1	100	nA	V <sub>CB</sub> = 60V
Emitter Cutoff Current	I <sub>EBO</sub>	—	<1	100	nA	V <sub>EB</sub> = 5.6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	—	<1	100	nA	$V_{CE} = 60V, V_{CES} = 60V$
	hfe	100	140	—		$I_{C} = 1mA, V_{CE} = 5V$
Ctatic Ferning Comment Transfer Datic (Nate 0)		100	150	300	_	I <sub>C</sub> = 500mA, V <sub>CE</sub> = 5V
Static Forward Current Transfer Ratio (Note 8)		80	120	—		$I_{C} = 1A, V_{CE} = 5V$
		30	40	_		$I_{C} = 2A, V_{CE} = 5V$
Collector Emitter Seturation Voltage (Note 9)	V <sub>CE(sat)</sub>	—	100	150	mV	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
Collector-Emitter Saturation Voltage (Note 8)			160	250	mv	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Base-Emitter Turn-On Voltage(Note 8)	V <sub>BE(on)</sub>	—	830	1000	mV	$I_C = 1A, V_{CE} = 5V$
Base-Emitter Saturation Voltage(Note 8)	V <sub>BE(sat)</sub>	_	965	1100	mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Output Capacitance	C <sub>obo</sub>	—	_	10	pF	V <sub>CB</sub> = 10V, f = 1MHz
Transition Frequency	f <sub>T</sub>	150	—	_	MHz	$\label{eq:VCE} \begin{split} V_{CE} &= 10V, \ I_C = 50mA, \\ f &= 100MHz \end{split}$

8. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%. Note:





### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

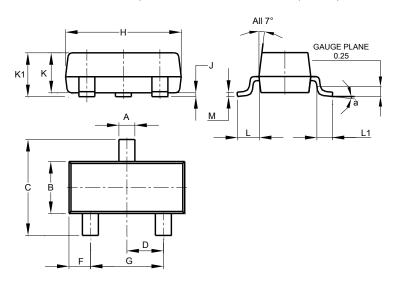






# **Package Outline Dimensions**

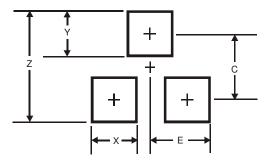
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
C	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
К	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
1	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	8°				
All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Y	0.9		
С	2.0		
E	1.35		





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